



Future Trends in Microelectronics

*From Nanophotonics to
Sensors and Energy*

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CONTENTS

Preface

S. Luryi, J. M. Xu, and A. Zaslavsky ix

1 OPTOELECTRONICS AND NANOPHOTONICS 1

Nanophotonics for Information Systems 5

Y. Fainman

**What Will Modern Photonics Contribute to the Development of
Future Optical Communication Technology?** 23

Djafar K. Mynbaev

Ultrafast Nanophotonic Devices For Optical Interconnects 43

N. N. Ledentsov

**Intersubband Quantum-Box Lasers: Progress
and Potential as Uncooled Mid-Infrared Sources** 49

*D. Botez, G. Tsvid, M. D'Souza, J. C. Shin, Z. Liu, J. H. Park,
J. Kirch, L. J. Mawst, M. Rathi, T. F. Kuech, I. Vurgaftman,
J. Meyer, J. Plant, G. Turner, and P. Zory*

**GaSb-based Type-I Laser Diodes
Operating at 3 μm and Beyond** 65

L. Shterengas, G. Kipshidze, T. Hosoda, and G. Belenky

**Bridging Optics and Electronics with Quantum
Cascade Lasers, Antennas, and Circuits** 75

J. Faist, C. Walther, M. Amanti, G. Scalari, M. Fischer, and M. Beck

**Towards Intersubband Polaritonics:
How Fast Can Light and Electrons Mate?** 85

*A. A. Anappara, L. Sorba, A. Tredicucci, G. Günter, A. Sell,
A. Leitenstorfer, R. Huber, S. De Liberato, C. Ciuti, and G. Biasiol*

**$\text{Si}_3\text{N}_4/\text{SiO}_2$ Planar Photonic Structures
Fabricated by Focused Ion Beam** 97

*L. A. M. Barea, F. Vallini, D. L. S. Figueira, A. Da Silva Filho,
N. C. Frateschi, and A. R. Vaz*

2 ELECTRONIC DEVICES AND SYSTEMS	105
Silicon-Based Devices and Materials for Nanoscale CMOS and Beyond-CMOS	109
<i>F. Balestra</i>	
Device Proposals Beyond Silicon CMOS	127
<i>P. M. Solomon</i>	
GeOI as a Platform for Ultimate Devices	141
<i>W. Van Den Daele, S. Cristoloveanu, E. Augendre, C. Le Royer, J.-F. Damlencourt, D. Kazazis, and A. Zaslavsky</i>	
Simulation of Self-Heating Effects in Different SOI MOS Architectures	159
<i>Enrico Sangiorgi, Marco Braccioli and Claudio Fiegna</i>	
Nanowires: Technology, Physics and Perspectives	171
<i>D. Grützmacher, Th. Schäpers, S. Mantl, S. Feste, Q. T. Zhao, H. Hardtdegen, R. Calarco, M. Lepsa, and N. Demarina</i>	
Emerging Nanotechnology for Integration of Nanostructures in Nanoelectronic Devices	183
<i>T. Baron, C. Agrafeil, F. Dhalluin, M. Kogelschitz, G. Cunge, T. Chevolleau, B. Salem, B. Salhi, H. Abed, A. Potié, L. Latu-Romain, C. Ternon, K. Aissou, L. Montès, Mur, G. Molas, B. De Salvo, E. Jalaguier, T. Ernst, P. Ferret, P. Gentile, and N. Pauc</i>	
Scrolled Si/SiGe Heterostructures as Building Blocks for Tube-Like Field-Effect Transistors	191
<i>N. V. Demarina and D. Grützmacher</i>	
Silicon Nanowire-Based Nonvolatile Memory Cells: Progress and Prospects	201
<i>Qiliang Li, X. Zhu, Y. Yang, D. E. Ioannou, J. S. Suehle, and C. A. Richter</i>	
Prospects and Challenges of Next-Generation Flash Memory Devices	211
<i>Jang-Sik Lee</i>	
Chalcogenide Glassy Semiconductors – Could They Replace Silicon in Memory Devices?	219
<i>K. D. Tsendin</i>	

Current Status and Recent Developments in RSFQ Processor Design	229
<i>M. Dorojevets</i>	
1/f Noise: The Funeral is Cancelled (or Postponed)	239
<i>M. E. Levinshtein and S. L. Romyantsev</i>	
3 PHYSICS, BIOLOGY, AND OTHER SISTER SCIENCES	247
Spin Hall Effect	251
<i>M. I. Dyakonov</i>	
Can Biology Provide Creative Solutions for Next-Generation Memory Devices?	265
<i>W. E. van den Berg and S. A. Kushner</i>	
Spin Screening of Magnetization Due to Inverse Proximity Effect in Superconducting/Ferromagnetic Bilayers	273
<i>V. Shelukhin, M. Karpovski, A. Palevski, J. Xia, A. Kapitulnik, and A. Tsukernik</i>	
Silicon for Spintronic Applications: Strain-Enhanced Valley Splitting	281
<i>V. Sverdlov, O. Baumgartner, T. Windbacher, and S. Selberherr</i>	
Graphene-Based Terahertz Devices: Concepts and Characteristics	293
<i>V. Ryzhii, M. Ryzhii, A. Satou, N. Ryabova, T. Otsuji, V. Mitin, F. T. Vasko, A. A. Dubinov, V. Y. Aleshkin, and M. S. Shur</i>	
Directed Self-Assembly – A Controllable Route to Optical and Electronic Devices Based on Single Nanostructures	307
<i>R. L. Williams, D. Dalacu, M. E. Reimer, K. Mnaymneh, V. Sazonova, P. J. Poole, G. C. Aers, R. Cheriton, S. Frédérick, D. Kim, J. Lapointe, P. Hawrylak, and M. Korkusiński</i>	
4 SENSORS, DETECTORS, AND ENERGY	317
Three-Dimensional Position-Sensitive Wide Bandgap Semiconductor Gamma-Ray Imaging Detectors	321
<i>Zhong He</i>	

Semiconductor Scintillator for Three-Dimensional Array of Radiation Detectors <i>Serge Luryi and Arsen Subashiev</i>	331
Semiconductor Gamma Radiation Detectors: Band Structure Effects in Energy Resolution <i>Arsen Subashiev and Serge Luryi</i>	347
The Future of Microelectronics is ... Macroelectronics <i>M. A. Alam, N. Pimparkar, and B. Ray</i>	365
An Integration Challenge: Information and Communication Technologies to Address Indoor Air Quality in Commercial Buildings <i>M. D'Iorio</i>	377
Quantum-Dot Infrared Photodetectors: In Search of the Right Design for Room-Temperature Operation <i>A. Sergeev, V. Mitin, L. H. Chien, and N. Vagidov</i>	385
Treating the Case of Incurable Hysteresis in VO₂ <i>M. Gurvitch, S. Luryi, A. Polyakov, and A. Shabalov</i>	395
Exploratory Studies on Silicon-Based Oxide Fuel Cell Power Sources Incorporating Ultrathin Nanostructured Platinum and Cerium Oxide Films as Anode Components <i>Bo-Kuai Lai, A. C. Johnson, H. Xiong, C. Ko, and S. Ramanathan</i>	411
INDEX	423